

Product Change Notification / LIAL-230THC778

_			_	_
	Э.	•	_	•
u	а		_	_

12-Jan-2022

Product Category:

Microprocessors

PCN Type:

Manufacturing Change

Notification Subject:

CCB 3700.006 Final Notice: Qualification of a new fabrication location TMGR of component U5 that is one of many components of the ATSAM5D27-WLSOMxx device family available in the 188L module (40.8x40.8x3.3mm).

Affected CPNs:

LIAL-230THC778_Affected_CPN_01122022.pdf LIAL-230THC778_Affected_CPN_01122022.csv

Notification Text:

PCN Status:Final Notification

PCN Type:Manufacturing change

Microchip Parts Affected:

Please open one of the files found in the Affected CPNs section.

Note: For your convenience Microchip includes identical files in two formats (.pdf and .xls)

Description of Change:Qualification of a new fabrication location TMGR of component U5 that is one of many components of the ATSAM5D27-WLSOMxx device family available in the 188L module (40.8x40.8x3.3mm). Please see attached to reveal the location of the component U5 on the module.

Pre and Post Change Summary:

	Pre Change	Post Change
Fabrication Site	Micrel Inc.	Microchip Technology Tempe –
T dolled tion one	(MCRL)	Fab 2 (TMGR)
Wafer size	6 inch wafers	8 inch wafers

Impacts to Data Sheet:None

Change ImpactNone

Reason for Change:To improve on time delivery and performance by qualifying a new fabrication location TMGR of component U5 that is one of many components of the ATSAM5D27-WLSOMxx device family available in the 188L module (40.8x40.8x3.3mm).

Change Implementation Status:In Progress

Estimated First Ship Date:January 30, 2022 (date code: 2206)

Note: Please be advised that after the estimated first ship date customers may receive pre and post change parts.

Time Table Summary:

		Ja	nuai	y 20	22	
Workweek	0	0	0	0	0	06
workweek	1	2	3	4	5	00
Qual Report						
Availability			Х			
Final PCN Issue						
Date			Х			
Estimated						
Implementation						х
Date						

Method to Identify Change: Traceability code

Qualification Report:Please open the attachments included with this PCN labeled as PCN_#_Qual_Report.

Revision History: January 12, 2022: Issued final notification.

The change described in this PCN does not alter Microchip's current regulatory compliance regarding the material content of the applicable product

Attachments:

PCN_LIAL-230THC778_ Qual Report.pdf PCN_LIAL-230THC778_Component location.pdf

Please contact your local Microchip sales office with questions or concerns regarding this notification.

Terms and Conditions:

If you wish to <u>receive Microchip PCNs via email</u> please register for our PCN email service at our <u>PCN</u> home page select register then fill in the required fields. You will find instructions about registering for Microchips PCN email service in the <u>PCN FAQ</u> section.

If you wish to <u>change your PCN profile</u>, <u>including opt out</u>, please go to the <u>PCN home page</u> select login and sign into your myMicrochip account. Select a profile option from the left navigation bar and make the applicable selections.



QUALIFICATION REPORT SUMMARY

RELIABILITY LABORATORY

PCN #: LIAL-23OTHC778

Date March 17, 2016

Qualification of a new fabrication location TMGR of component U5 that is one of many components of the ATSAM5D27-WLSOMxx device family available in the 188L module (40.8x40.8x3.3mm). This is a qualification by similarity(QBS).

Purpose: Qualification of a new fabrication location TMGR of component U5 that is one of many components of the ATSAM5D27-WLSOMxx device family available in the 188L module (40.8x40.8x3.3mm). This is a qualification by similarity (QBS).

CCB No: 1737.06 and 3700.006

PART NUMBER	PACKAGE TYPE	ASSEMBLY LOCATION	WAFER SIZE	PROCESS NAME
MIC4102YM /27801	SOIC-8L	STARS, THAILAND	8"	B2M2

DIE QUALIFICATION RESULTS

TEST DESCRIPTION	METHOD/CONDITIONS	DATE CODE	LOT ID.	168 HR Rej/ss	500 HR Rej/ss	1000 HR Rej/ss	COMMENTS
HTOL	JESD22, Method 108 TA= + 125°C	1546	V416242557.100MQA	0/77	0/77	0/77	
High Temperature Operating Life Test		1547	V416242557.110MQD	0/77	0/77	0/77	
	Vdd = + 16V HB = + 116V HS = + 100V	1550	V416242557.200MQD	0/77	0/77	0/77	

HTOL Test Note:

The 4102 has a level shift circuit. When Vdd is not powered during VHBHS_ABS_MAX leakage test, gates of level shift transistors could float making their operating state unstable. Test program was changed to hold Vdd to same potential as HB when measuring HB to HS leakage. All parts pass this test condition.

ELECTROSTATIC DISCHARGE

TEST DESCRIPTION	METHOD/CONDITIONS	DATE CODE	LOT ID.	STRESS	RESULT Rej/ss	COMMENTS
ESD-HBM Human Body Model ATE Test @ Room +25C	R= 1500 Ohms C= 100 pF 1X +/- Voltage	1546	V416242557.100MQA	+/-2000V	0/3	Note: ESD ratings are device specific. All Products qualified on the 8" Micrel process technologies will
ESD-CDM Charged Device Model ATE Test @ Room +25C	JESD22-C101 1X +/- Voltage	1546	V416242557.100MQA	+/-1500V	0/3	have the same or better ESD and Latch-up performance as the 6" San Jose Products.
TEST DESCRIPTION	METHOD/CONDITIONS	DATE CODE	LOT ID.	STRESS	RESULT Rej/ss	COMMENTS

PACKAGE QUALIFIC	ATION RESULTS				
TEST DESCRIPTION	METHOD/CONDITIONS	DATE CODE	LOT ID.	Rej/ss	COMMENTS
Level 1 Pre-conditioning Flow	JESD22-A113	1546	V416242557.100MQA	0/320	
		1547	V416242557.110MQD	0/145	
		1550	V416242557.200MQD	0/145	
TEST DESCRIPTION	METHOD/CONDITIONS	DATE CODE	LOT ID.	96 HR Rej/ss	COMMENTS
PRESSURE POT	JESD22-A102	1546	V416242557.100MQA	0/45	
With Level 1 Pre- conditioning	Ta = +121°C/100%RH	1547	V416242557.110MQD	0/45	
Tpeak + 260°C 3X Reflow	15 PSIG	1550	V416242557.200MQD	0/45	
TEST DESCRIPTION	METHOD/CONDITIONS	DATE CODE	LOT ID.	96 HR Rej/ss	COMMENTS
HAST	JESD22-A110 (BIASED)	1546	V416242557.100MQA	0/45	
With Level 1 Pre- conditioning	Ta= +130°C/85%RH	1547	V416242557.110MQD	0/45	
Tpeak + 260°C 3X Reflow	Vdd = +16V	1550	V416242557.200MQD	0/45	
	HB/HS = +38V				
TEST DESCRIPTION	METHOD/CONDITIONS	DATE CODE	LOT ID.	500 CY Rej/ss	COMMENTS
TEMP CYCLE	JESD22-A104	1546	V416242557.100MQA	0/45	
				0/45	
With Level 1 Pre- conditioning Theak + 260°C 3X Reflow	Ta = -65°C / +150°C	1547	V416242557.110MQD	0/45	
	Ta = -65°C / +150°C	1547 1550	V416242557.110MQD V416242557.200MQD	0/45	
conditioning	Ta = -65°C / +150°C METHOD/CONDITIONS				COMMENTS
conditioning Tpeak + 260°C 3X Reflow		1550 DATE	V416242557.200MQD	0/45 1000 HR	COMMENTS
conditioning Tpeak + 260°C 3X Reflow TEST DESCRIPTION HTSL High Temperature Storage Life	METHOD/CONDITIONS	1550 DATE CODE	V416242557.200MQD LOT ID.	0/45 1000 HR Rej/ss	COMMENTS
conditioning Tpeak + 260°C 3X Reflow TEST DESCRIPTION HTSL High Temperature	METHOD/CONDITIONS JESD22-A103	1550 DATE CODE 1546	V416242557.200MQD LOT ID. V416242557.100MQA	0/45 1000 HR Rej/ss	COMMENTS
conditioning Tpeak + 260°C 3X Reflow TEST DESCRIPTION HTSL High Temperature Storage Life With Level 1 Pre-	METHOD/CONDITIONS JESD22-A103	1550 DATE CODE 1546 1547	V416242557.200MQD LOT ID. V416242557.100MQA V416242557.110MQD	0/45 1000 HR Rej/ss	COMMENTS
conditioning Tpeak + 260°C 3X Reflow TEST DESCRIPTION HTSL High Temperature Storage Life With Level 1 Preconditioning	METHOD/CONDITIONS JESD22-A103 Ta = +150°C	1550 DATE CODE 1546 1547 1550 DATE	V416242557.200MQD LOT ID. V416242557.100MQA V416242557.110MQD V416242557.200MQD	0/45 1000 HR Rej/ss 0/76	
conditioning Tpeak + 260°C 3X Reflow TEST DESCRIPTION HTSL High Temperature Storage Life With Level 1 Preconditioning TEST DESCRIPTION HTSL High Temperature Storage Life With Level 1 Preconditioning	METHOD/CONDITIONS JESD22-A103 Ta = +150°C METHOD/CONDITIONS	1550 DATE CODE 1546 1547 1550 DATE CODE 1546 1547	V416242557.200MQD LOT ID. V416242557.100MQA V416242557.110MQD V416242557.200MQD LOT ID. V416242557.100MQA V416242557.110MQD	0/45 1000 HR Rej/ss 0/76 500 HR Rej/ss	
conditioning Tpeak + 260°C 3X Reflow TEST DESCRIPTION HTSL High Temperature Storage Life With Level 1 Pre- conditioning TEST DESCRIPTION HTSL High Temperature Storage Life With Level 1 Pre- conditioning	METHOD/CONDITIONS JESD22-A103 Ta = +150°C METHOD/CONDITIONS JESD22-A103 Ta = +175°C	1550 DATE CODE 1546 1547 1550 DATE CODE 1546 1547 1550	V416242557.200MQD LOT ID. V416242557.100MQA V416242557.110MQD V416242557.200MQD LOT ID. V416242557.110MQA V416242557.110MQD V416242557.200MQD	0/45 1000 HR Rej/ss 0/76 500 HR Rej/ss 0/76	COMMENTS
conditioning Tpeak + 260°C 3X Reflow TEST DESCRIPTION HTSL High Temperature Storage Life With Level 1 Preconditioning TEST DESCRIPTION HTSL High Temperature Storage Life With Level 1 Preconditioning	METHOD/CONDITIONS JESD22-A103 Ta = +150°C METHOD/CONDITIONS JESD22-A103	1550 DATE CODE 1546 1547 1550 DATE CODE 1546 1547 1550 All mold of material files	V416242557.200MQD LOT ID. V416242557.100MQA V416242557.110MQD V416242557.200MQD LOT ID. V416242557.110MQD V416242557.110MQD V416242557.200MQD ompounds used by Micrel relationships	0/45 1000 HR Rej/ss 0/76 500 HR Rej/ss 0/76	COMMENTS ard. See the UL website on-line list of a Certificate of Compliance from the

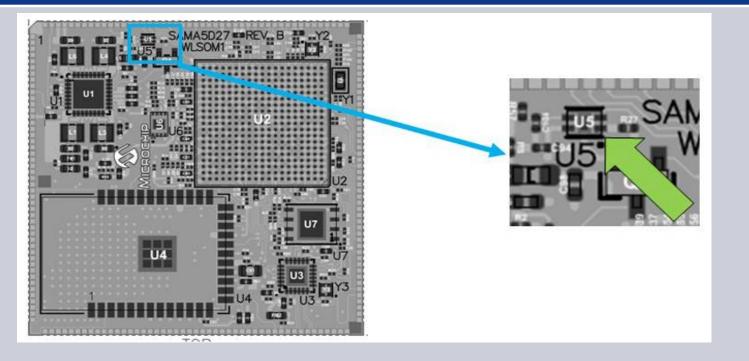
CCB 3700.006 PCN#: LIAL-23OTHC778



A Leading Provider of Smart, Connected and Secure Embedded Control Solutions



U5 Component Location





LIAL-23OTHC778 - CCB 3700.006 Final Notice: Qualification of a new fabrication location TMGR of compon

Affected Catalog Part Numbers(CPN)

ATSAMA5D27-WLSOM1 ATSAMA5D27-WLSOM21